BLP05H6700XR; BLP05H6700XRG Power LDMOS transistor

AMPLEON

Rev. 2 — 13 September 2018

Product data sheet

Product profile

1.1 General description

A 700 W extra rugged LDMOS power transistor optimized for broadcast, industrial, aerospace and defense applications in the HF to 600 MHz band.

Application information Table 1.

| Test signal | f | V _{DS} | P _L | G _p | η _D |
|-------------|-------|-----------------|----------------|----------------|----------------|
| | (MHz) | (V) | (W) | (dB) | (%) |
| pulsed RF | 108 | 50 | 700 | 26 | 75 |

1.2 Features and benefits

- Easy power control
- Integrated dual sided ESD protection enables class C operation and complete switch off of the transistor
- Excellent ruggedness VSWR 65 : 1
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (HF to 600 MHz)
- 50 V operation for easy broadband matching
- Package available in both straight leads and gull wing form
- For RoHS compliance see the product details on the Ampleon website

1.3 Applications

- Industrial, scientific and medical applications
- Broadcast transmitter applications
- Aerospace and defense applications

2. Pinning information

Table 2. Pinning

| Description | Simplified outline | Graphic symbol |
|---------------------|---|---|
| 5700XR (SOT1138-3) | | |
| gate 2 | | |
| gate 1 | 4 3 | 4 |
| drain 1 | | 1 1 |
| drain 2 | | 5 |
| source [1] | | 2— |
| | 1 2 | , 'T |
| | | aaa-003574 |
| 5700XRG (SOT1204-3) | | |
| gate 2 | | _ |
| gate 1 | 4 3 | 4 |
| drain 1 | | 1_ |
| drain 2 | | 5 |
| source [1] | 1 2 | 2— |
| | | 3 |
| | | aaa-003574 |
| | gate 2 gate 1 drain 1 drain 2 source [1] 700XRG (SOT1204-3) gate 2 gate 1 drain 1 drain 2 | gate 2 gate 1 drain 1 drain 2 source [1] 7700XRG (SOT1204-3) gate 2 gate 1 drain 1 drain 2 |

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

| Type number | Package | ackage | | |
|---------------|---------|---|-----------|--|
| | Name | ame Description V | | |
| BLP05H6700XR | - | plastic, heatsink small outline package; 4 leads (flat) | SOT1138-3 | |
| BLP05H6700XRG | - | plastic, heatsink small outline package; 4 leads | | |

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-------------------|----------------------|------------|-----|------|------|
| V_{DS} | drain-source voltage | | - | 135 | V |
| V_{GS} | gate-source voltage | | -6 | +11 | V |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| T _{case} | case temperature | | - | 150 | °C |
| Tj | junction temperature | [1] | - | 225 | °C |

^[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

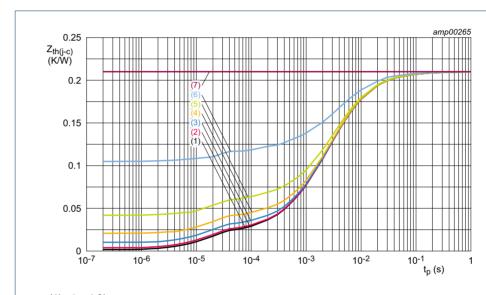
BLP05H6700XR_H6700XRG

5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | | Тур | Unit |
|-------------------------|---|--|--------|-------|------|
| R _{th(j-case)} | thermal resistance from junction to case | T _j = 150 °C | [1][2] | 0.21 | K/W |
| Z _{th(j-case)} | transient thermal impedance from junction to case | T_j = 150 °C; t_p = 100 μs; $δ$ = 20 % | [3] | 0.064 | K/W |

- [1] T_i is the junction temperature.
- [2] $R_{th(j-c)}$ is measured under RF conditions.
- [3] See Figure 1.



- (1) $\delta = 1 \%$
- (2) $\delta = 2 \%$
- (3) $\delta = 5 \%$
- (4) $\delta = 10 \%$
- (5) $\delta = 20 \%$
- (6) $\delta = 50 \%$
- (7) $\delta = 100 \% (DC)$

Fig 1. Transient thermal impedance from junction to case as a function of pulse duration

6. Characteristics

Table 6. DC characteristics

 T_i = 25 °C per section; unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|----------------------------------|--|------|------|------|------|
| V _{(BR)DSS} | drain-source breakdown voltage | $V_{GS} = 0 \text{ V}; I_D = 2.75 \text{ mA}$ | 135 | - | - | V |
| V _{GS(th)} | gate-source threshold voltage | V _{DS} = 10 V; I _D = 275 mA | 1.33 | 1.9 | 2.33 | V |
| V_{GSq} | gate-source quiescent voltage | $V_{DS} = 50 \text{ V}; I_{D} = 50 \text{ mA}$ | - | 2.1 | - | V |
| I _{DSS} | drain leakage current | V _{GS} = 0 V; V _{DS} = 50 V | - | - | 1.4 | μΑ |
| I _{DSX} | drain cut-off current | $V_{GS} = V_{GS(th)} + 3.75 V;$ $V_{DS} = 10 V$ | - | 36 | - | Α |
| I _{GSS} | gate leakage current | V _{GS} = 11 V; V _{DS} = 0 V | - | - | 140 | nA |
| R _{DS(on)} | drain-source on-state resistance | $V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 9.625 \text{ A}$ | - | 0.16 | - | Ω |

Table 7. AC characteristics

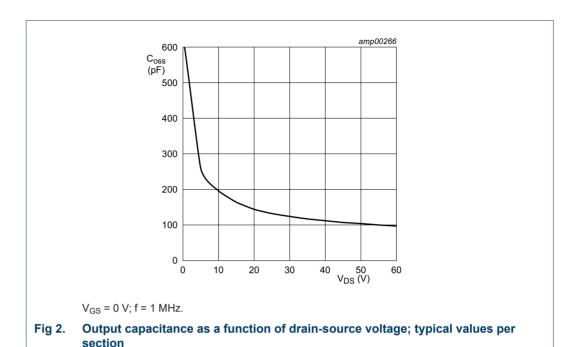
 T_i = 25 °C per section; unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|----------------------|--|-----|------|-----|------|
| C _{rs} | feedback capacitance | $V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$ | - | 2.75 | - | pF |
| C _{iss} | input capacitance | V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz | - | 297 | - | pF |
| C _{oss} | output capacitance | V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz | - | 104 | - | pF |

Table 8. RF characteristics

Test signal: pulsed RF; t_p = 100 μ s; δ = 20 %; f = 108 MHz; RF performance at V_{DS} = 50 ; I_{Dq} = 100 mA; T_{case} = 25 °C; unless otherwise specified; in a class-AB production test circuit.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------|-------------------|------------------------|-----|-----|-----|------|
| Gp | power gain | P _L = 700 W | 25 | 26 | - | dB |
| RLin | input return loss | P _L = 700 W | - | -13 | - | dB |
| η_{D} | drain efficiency | P _L = 700 W | 72 | 75 | - | % |



Test information 7.

7.1 Ruggedness in class-AB operation

The BLP05H6700XR and the BLP05H6700XRG are capable of withstanding a load mismatch corresponding to VSWR > 65: 1 through all phases under the following conditions: $V_{DS} = 50 \text{ V}$; $I_{Dq} = 100 \text{ mA}$; $P_L = 700 \text{ W}$ pulsed; f = 108 MHz.

7.2 Impedance information

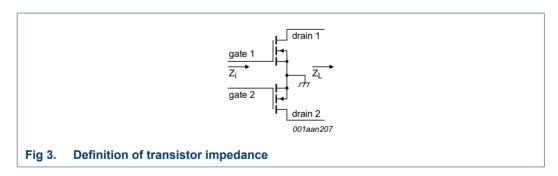


Table 9. Typical push-pull impedance

Simulated Z_i and Z_L device impedance; impedance info at V_{DS} = 50 V and P_L = 700 W.

| f | Z_i | Z_{L} |
|-------|-------------|------------|
| (MHz) | (Ω) | (Ω) |
| 108 | 5.9 – j19.1 | 5.5 + j1.1 |

7.3 Test circuit

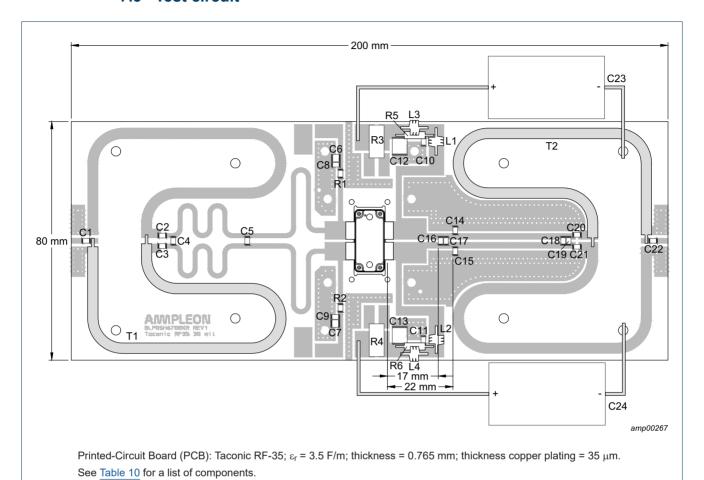


Fig 4. Component layout for class-AB production test circuit

Table 10. List of components For test circuit see Figure 4.

| Component | Description | Value | Remarks |
|-----------|-----------------------------------|---------------|----------|
| C1 | multilayer ceramic chip capacitor | 510 pF [1] | ATC 100B |
| C2, C3 | multilayer ceramic chip capacitor | 62 pF [1] | ATC 100B |
| C4 | multilayer ceramic chip capacitor | 20 pF [1] | ATC 100B |
| C5 | multilayer ceramic chip capacitor | 160 pF [1] | ATC 100B |
| C6, C7 | multilayer ceramic chip capacitor | 4.7 μF, 100 V | |
| C8, C9 | multilayer ceramic chip capacitor | 820 pF [1] | ATC 100B |
| C10, C11 | multilayer ceramic chip capacitor | 820pF [1] | ATC 100B |
| C12, C13 | multilayer ceramic chip capacitor | 4.7 μF, 100 V | |
| C14, C15 | multilayer ceramic chip capacitor | 91 pF [1] | ATC 100B |
| C16 | multilayer ceramic chip capacitor | 36 pF [1] | ATC 100B |
| C17 | multilayer ceramic chip capacitor | 22 pF [1] | ATC 100B |
| C18, C19 | multilayer ceramic chip capacitor | 47 pF [1] | ATC 100B |
| C20, C21 | multilayer ceramic chip capacitor | 120 pF [1] | ATC 100B |

Table 10. List of components ...continued For test circuit see Figure 4.

| Component | Description | Value | Remarks |
|-----------|-----------------------------------|--------------------|--------------------|
| C22 | multilayer ceramic chip capacitor | 220 pF [1] | ATC 100B |
| C23, C24 | electrolytic capacitor | 2200 μF, 64 V | |
| L1, L2 | air inductor | 10 turns, d = 2 mm | 0.5 mm copper wire |
| L3, L4 | air inductor | 6 turns, d = 2 mm | 0.5 mm copper wire |
| R1, R2 | resistor | 4.7 kΩ | SMD 1206 |
| R3, R4 | shunt resistor | 0.01 Ω | FC4L110R010FER |
| R5, R6 | metal film resistor | 10 Ω, 0.6 W | |
| T1, T2 | semi rigid coax | 50 Ω, 160 mm | EZ 86-TP/M17 |

^[1] American Technical Ceramics type 100B or capacitor of same quality.

7.4 Graphical data

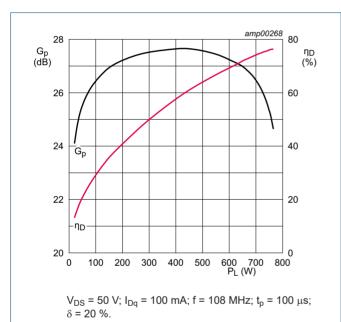
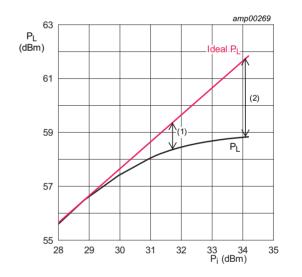


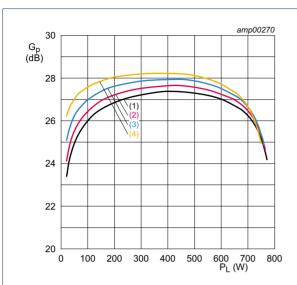
Fig 5. Power gain and drain efficiency as function of output power; typical values



 V_{DS} = 50 V; I_{Dq} = 100 mA; f = 108 MHz; t_p = 100 $\mu s;$ δ = 20 %.

- (1) $P_{L(1dB)} = 58.4 \text{ dBm } (692 \text{ W})$
- (2) $P_{L(3dB)} = 58.8 \text{ dBm } (765 \text{ W})$

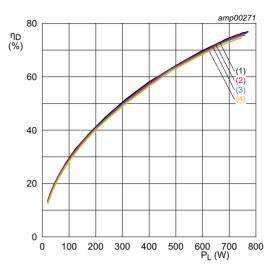
Fig 6. Output power as a function of input power; typical values



 V_{DS} = 50 V; f = 108 MHz; t_p = 100 μ s; δ = 20 %.

- (1) $I_{Dq} = 50 \text{ mA}$
- (2) $I_{Dq} = 100 \text{ mA}$
- (3) $I_{Dq} = 200 \text{ mA}$
- (4) $I_{Dq} = 400 \text{ mA}$

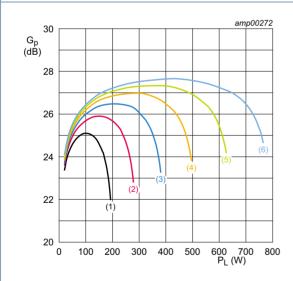
Fig 7. Power gain as a function of output power; typical values



 V_{DS} = 50 V; f = 108MHz; t_p = 100 μ s; δ = 20 %.

- (1) $I_{Dq} = 50 \text{ mA}$
- (2) $I_{Dq} = 100 \text{ mA}$
- (3) $I_{Dq} = 200 \text{ mA}$
- (4) $I_{Dq} = 400 \text{ mA}$

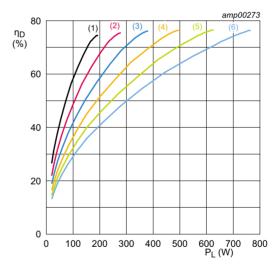
Fig 8. Drain efficiency as a function of output power; typical values



 I_{Dq} = 100 mA; f = 108 MHz; t_p = 100 μ s; δ = 20 %.

- (1) $V_{DS} = 25 \text{ V}$
- (2) $V_{DS} = 30 \text{ V}$
- (3) $V_{DS} = 35 \text{ V}$
- (4) $V_{DS} = 40 \text{ V}$
- (5) $V_{DS} = 45 \text{ V}$
- (6) $V_{DS} = 50 \text{ V}$

Fig 9. Power gain as a function of output power; typical values



 I_{Dq} = 100 mA; f = 108 MHz; t_p = 100 μ s; δ = 20 %.

- (1) $V_{DS} = 25 \text{ V}$
- (2) $V_{DS} = 30 \text{ V}$
- (3) $V_{DS} = 35 \text{ V}$
- (4) $V_{DS} = 40 \text{ V}$
- (5) $V_{DS} = 45 V$
- (6) $V_{DS} = 50 \text{ V}$

Fig 10. Drain efficiency as a function of output power; typical values

8. Package outline

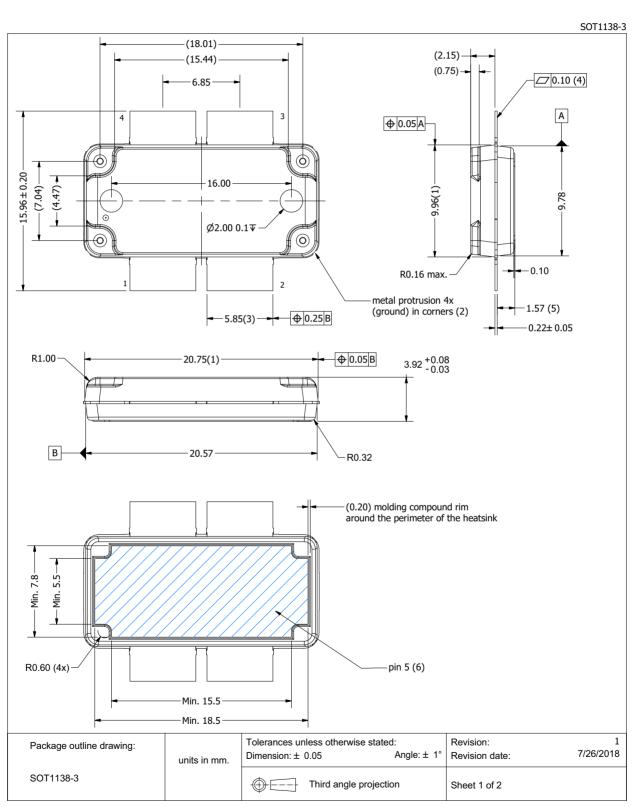


Fig 11. Package outline SOT1138-3 (sheet 1 of 2)

SOT1138-3

| | Drawing Notes | | | | |
|-------|---|--|--|--|--|
| Items | Description | | | | |
| | Dimensions are excluding mold protrusion. All areas located adjacent to the leads have a maximum mold protrusion of 0.2 | | | | |
| (1) | mm (per side) and max. 0.62 mm in length. | | | | |
| | At all other areas the mold protrusion is maximum 0.15 mm per side. See also detail B. | | | | |
| (2) | The metal protrusion (tie bars) in the corner will not stick out of the molding compound protrusions (detail A). | | | | |
| (3) | The lead dambar (metal) protrusions are not included. Add 0.14 mm max to the total lead dimension at the dambar location. | | | | |
| (4) | The lead coplanarity over all leads is 0.1 mm maximum. | | | | |
| (5) | Dimension is measured 0.5 mm from the edge of the top package body. | | | | |
| (6) | (6) The hatched area indicates the exposed metal heatsink. | | | | |
| (7) | The leads and exposed heatsink are plated with matte Tin (Sn). | | | | |

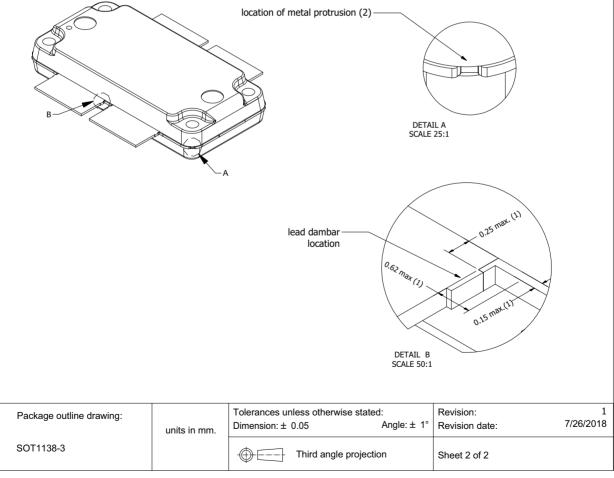


Fig 12. Package outline SOT1138-3 (sheet 2 of 2)

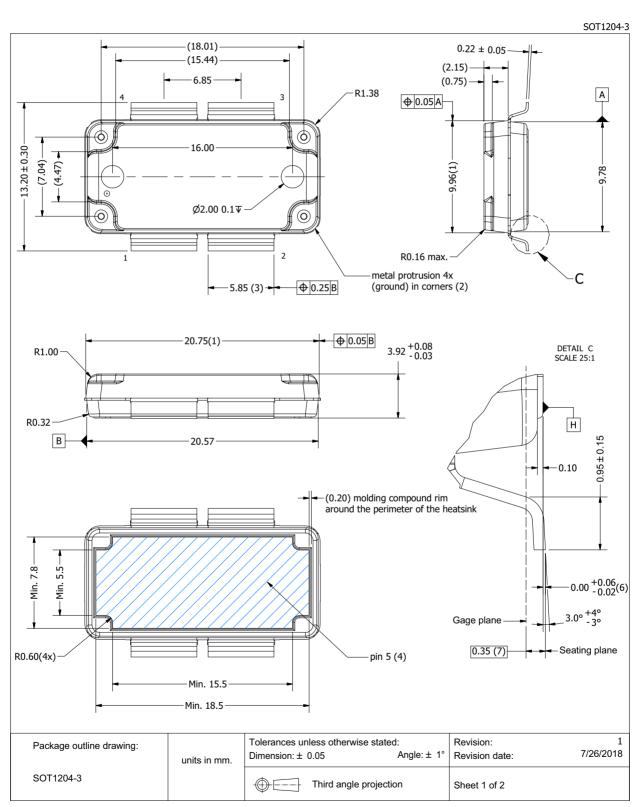


Fig 13. Package outline SOT1204-3 (sheet 1 of 2)

SOT1204-3

| Drawing Notes | | | | |
|---------------|--|--|--|--|
| Items | Description | | | |
| | Dimensions are excluding mold protrusion. All areas located adjacent to the leads have a maximum mold protrusion of 0.28 | | | |
| (1) | mm (per side) and 0.62 mm max. in length. | | | |
| | At other areas the mold protrusion is maximum 0.15 mm per side. See also detail B. | | | |
| (2) | The metal protrusion (tie bars) in the corner will not stick out of the molding compound protrusions (detail A). | | | |
| (3) | The lead dambar (metal) protrusions are not included. Add 0.14 mm max to the total lead dimension at the dambar location | | | |
| (4) | The hatched area indicated the exposed heatsink. | | | |
| (5) | The leads and exposed heatsink are plated with matte Tin (Sn). | | | |
| (6) | Dimension is measured with respect to the bottom of the heatsink Datum H. Positive value means that the bottom of the | | | |
| | heatsink is higher than the bottom of the lead. | | | |
| (7) | Gage plane (foot length) to be measured from the seating plane. | | | |

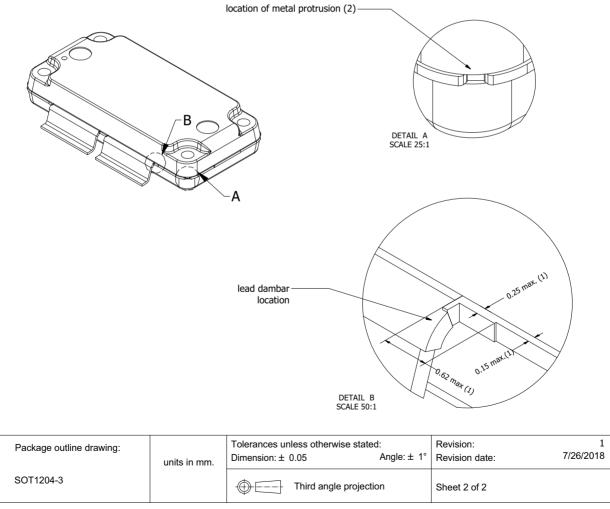


Fig 14. Package outline SOT1204-3 (sheet 2 of 2)

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 11. ESD sensitivity

| ESD model | Class |
|--|---------|
| Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002 | C2A [1] |
| Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001 | 2 [2] |

- [1] CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V.
- [2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V.

10. Abbreviations

Table 12. Abbreviations

| Acronym | Description |
|---------|--|
| ESD | ElectroStatic Discharge |
| HF | High Frequency |
| LDMOS | Laterally Diffused Metal-Oxide Semiconductor |
| MTF | Median Time to Failure |
| SMD | Surface Mounted Device |
| RoHS | Restriction of Hazardous Substances |
| VSWR | Voltage Standing Wave Ratio |

11. Revision history

Table 13. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | |
|------------------------------|---|--------------------|---------------|---------------------------|--|
| BLP05H6700XR_H6700XRG v.2 | 20180913 | Product data sheet | - | BLP05H6700XR_H6700XRG v.1 | |
| Modifications | Table 2 on page 2: package outline versions changed to SOT1138-3 and SOT1204-3 Table 3 on page 2: package outline versions changed to SOT1138-3 and SOT1204-3 Figure 4 on page 6: figure updated Section 8 on page 9: package outline versions changed from SOT1138-2 and SOT1204-2 to SOT1138-3 and SOT1204-3 | | | | |
| BLP05H6700XR_H6700XRG v.1 | | Product data sheet | - | - | |

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12.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
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